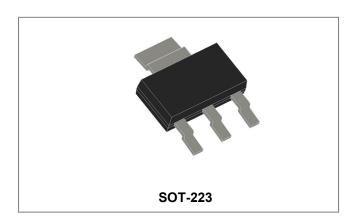






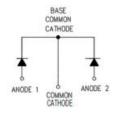
### **20CJQ100 SCHOTTKY RECTIFIER**



#### **Features**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



#### **Applications**

- Switching power supply
- Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### **Maximum Ratings:**

| Characteristics  | Symbol   | Condition                                       | Max.                        | Units |
|--|--|---|-----------------------------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | -   | 100                         | V     |
| Average Rectified Forward Current  | I <sub>F (AV)</sub>                                    | 50% duty cycle @Tc=126°C, rectangular wave form | 1(Per Leg)<br>2(Per Device) | Α     |
| Peak One Cycle Non-Repetitive Surge Current(Per Leg)                             | I <sub>FSM</sub>                                       | 8.3ms, Half Sine pulse, T <sub>C</sub> = 25 °C  | 26                          | Α     |

#### **Electrical Characteristics:**

| Characteristics                    | Symbol          | Condition  | Тур.         | Max.      | Units |
|------------------------------------|-----------------|--|--------------|-----------|-------|
| Forward Voltage Drop<br>(Per Leg)* | V <sub>F1</sub> | @ 1A, Pulse, T <sub>J</sub> = 25 °C<br>@ 2A, Pulse, T <sub>J</sub> = 25 °C   | 0.79<br>0.87 | 0.85<br>- | V     |
|                                    | V <sub>F2</sub> | @ 1A, Pulse, T <sub>J</sub> = 125 °C<br>@ 2A, Pulse, T <sub>J</sub> = 125 °C | 0.67<br>0.75 | 0.75<br>- | V     |
| Reverse Current<br>(Per Leg)*      | I <sub>R1</sub> | $@V_R = \text{rated } V_R$<br>$T_J = 25  ^{\circ}\text{C}$                   | 0.03         | 100       | uA    |
|                                    | I <sub>R2</sub> | $@V_R = \text{rated } V_R$<br>$T_J = 125  ^{\circ}\text{C}$                  | 0.003        | 1.0       | mA    |
| Junction Capacitance(Per Leg)      | Ст              | $@V_R = 5V, T_C = 25 °C$<br>$f_{SIG} = 1MHz$                                 | 26           | 45        | pF    |

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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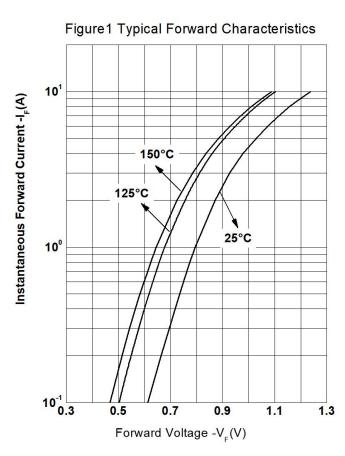


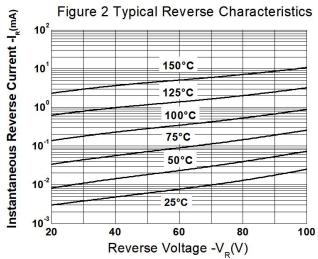


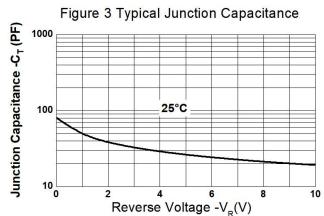
# **Thermal-Mechanical Specifications:**

| Characteristics                                | Symbol            | Condition    | Specification | Units |
|--|-------------------|--------------|---------------|-------|
| Junction Temperature                           | TJ                | -            | -55 to +150   | °C    |
| Storage Temperature                            | T <sub>stg</sub>  | -            | -55 to +150   | °C    |
| Typical Thermal Resistance Junction to Lead    | R <sub>θ</sub> JL | DC operation | 25            | °C/W  |
| Typical Thermal Resistance Junction to Ambient | R <sub>0</sub> JA | DC operation | 65            | °C/W  |
| Approximate Weight                             | wt                | -            | 0.13          | g     |
| Case Style                                     | SOT-223           |              |               |       |

## **Ratings and Characteristics Curves**







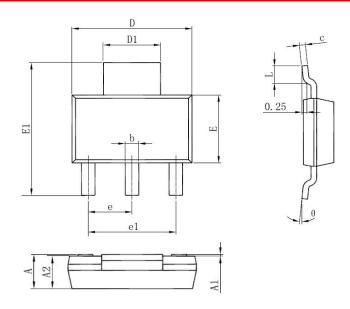
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### **Mechanical Dimensions SOT-223**



| CVMDOL | Millimeters |       | Inches     |       |  |
|--------|-------------|-------|------------|-------|--|
| SYMBOL | MIN.        | MAX.  | MIN.       | MAX.  |  |
| А      | 1.520       | 1.800 | 0.060      | 0.071 |  |
| A1     | 0.000       | 0.100 | 0.000      | 0.004 |  |
| A2     | 1.500       | 1.700 | 0.059      | 0.067 |  |
| b      | 0.660       | 0.820 | 0.026      | 0.032 |  |
| С      | 0.250       | 0.350 | 0.010      | 0.014 |  |
| D      | 6.200       | 6.400 | 0.244      | 0.252 |  |
| D1     | 2.900       | 3.100 | 0.114      | 0.122 |  |
| Е      | 3.300       | 3.700 | 0.130      | 0.146 |  |
| E1     | 6.830       | 7.070 | 0.269      | 0.278 |  |
| е      | 2.300(BSC)  |       | 0.091(BSC) |       |  |
| e1     | 4.500       | 4.700 | 0.177      | 0.185 |  |
| L      | 0.900       | 1.150 | 0.035      | 0.045 |  |
| θ      | 0°          | 10°   | 0°         | 10°   |  |

## **Ordering Information**

| Device     | Package              | Shipping       |
|------------|----------------------|----------------|
| 20CJQ100   | SOT-223<br>(Pb-Free) | 3000pcs / reel |
| 20CJQ100TR | SOT-223<br>(Pb-Free) | 3000pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



Where XXXXX is YYWWL

 20CJQ100
 = Part Name

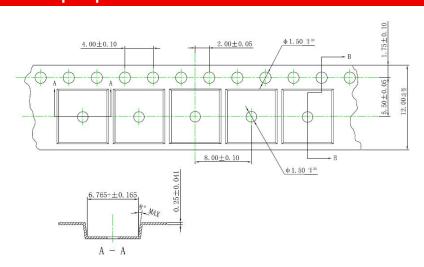
 SSG
 = SSG

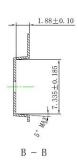
 YY
 = Year

 WW
 = Week

 L
 = Lot Number

### **Carrier Tape Specification SOT-223**





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